

20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current 500mA

Features

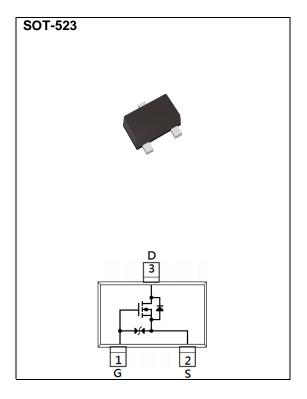
- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 standard

Mechanical Data

• Case: SOT-523 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.002 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage	V _G s	<u>+</u> 10			
Continuous Drain Current(Note 4)		I _D	500	mA	
Pulsed Drain Current ^(Note 1)		I _{DM}	1000		
Power Dissipation	T _a =25°C	P _D	300	mW	
	Derate above 25°C		2.4	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient ^(Note 3,4)		RөJA	417	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static			1		•		
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V, I _D =250uA 20		20	-	-	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	0.3	0.64	0.9	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =500mA	-	310	400		
		V _{GS} =2.5V, I _D =200mA	-	360	650	mΩ	
		V _{GS} =1.8V, I _D =100mA	-	430	800		
		V _{GS} =1.5V, I _D =50mA	-	510	1200	-	
		V _{GS} =1.2V, I _D =20mA	-	710	3000		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =16V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	-	<u>+</u> 10		
Dynamic ^(Note 5)							
Total Gate Charge	Qg	V _{DS} =10V, I _D =500mA, V _{GS} =4.5V ^(Note 1,2)	-	1.4	-	nC	
Gate-Source Charge	Qgs		-	0.22	-		
Gate-Drain Charge	Q_{gd}	VGS=4.5 V(1000 1)2/	-	0.21	-		
Input Capacitance	Ciss		-	67	-		
Output Capacitance	Coss	V _{DS} =10V, V _{GS} =0V, f=1MHZ	-	19	-	pF	
Reverse Transfer Capacitance	Crss	I= IIVIIIZ	-	6	-		
Turn-On Delay Time	td _(on)	\/ 40\/ I 450m A	-	2.8	-		
Turn-On Rise Time	tr	V _{DD} =10V, I _D =150mA, V _{GS} =4.0V,	-	20	-	ns	
Turn-Off Delay Time	td _(off)	VGS=4.0V, RG= $10\Omega^{\text{(Note 1,2)}}$	-	23	-		
Turn-Off Fall Time	tf	RG=1002(Note 1,2)	-	23	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	500	mA	
Diode Forward Voltage	V _{SD}	I _S =500mA, V _{GS} =0V	-	0.87	1.3	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

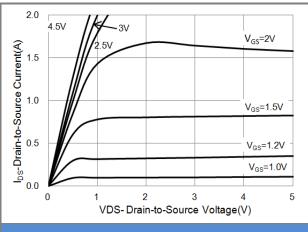


Fig.1 On-Region Characteristics

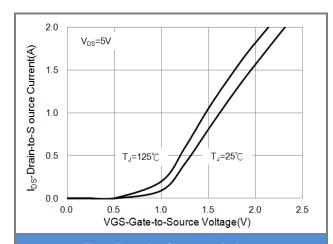


Fig.2 Transfer Characteristics

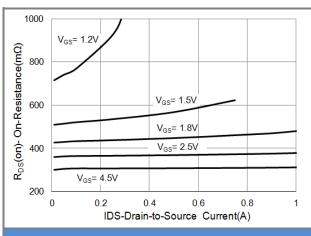


Fig.3 On-Resistance vs. Drain Current

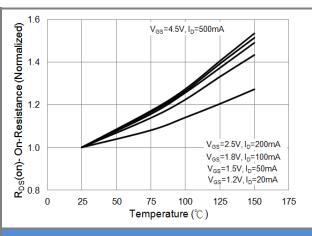
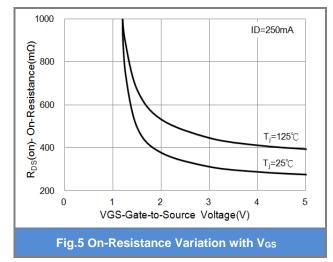
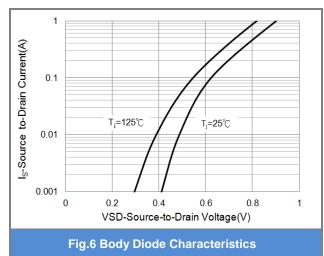


Fig.4 On-Resistance vs. Junction temperature







TYPICAL CHARACTERISTIC CURVES

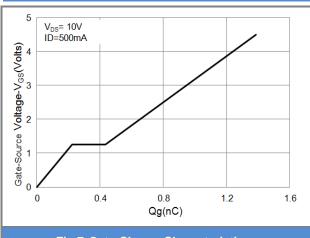


Fig.7 Gate-Charge Characteristics

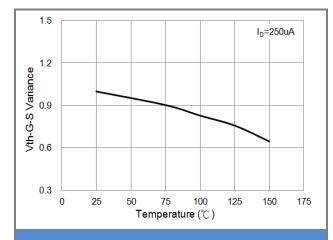


Fig.8 Threshold Voltage Variation with Temperature

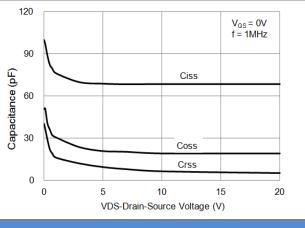


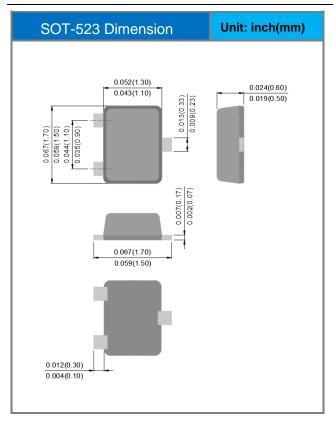
Fig.9 Capacitance vs. Drain-Source Voltage

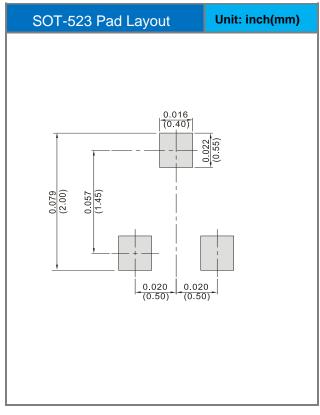


Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJE8408-AU	SOT-523	4K pcs / 7" reel	E08	

Packaging Information & Mounting Pad Layout







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